

# MC74LVX50

## Hex Buffer

The MC74LVX50 is an advanced high speed CMOS buffer fabricated with silicon gate CMOS technology.

The internal circuit is composed of three stages, including a buffered output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7 V, allowing the interface of 5 V systems to 3 V systems.

- High Speed:  $t_{PD} = 4.1$  ns (Typ) at  $V_{CC} = 3.3$  V
- Low Power Dissipation:  $I_{CC} = 2$   $\mu$ A (Max) at  $T_A = 25^\circ$ C
- High Noise Immunity:  $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2 V to 3.6 V Operating Range
- Low Noise:  $V_{OLP} = 0.5$  V (Max)

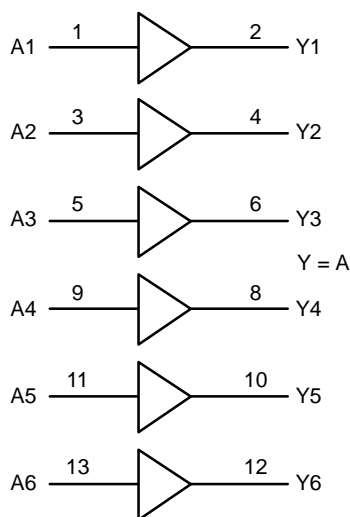


Figure 1. Logic Diagram

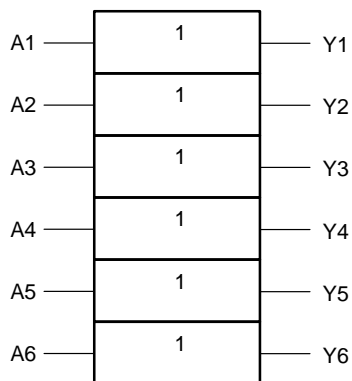
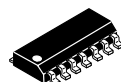


Figure 2. Logic Symbol

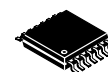


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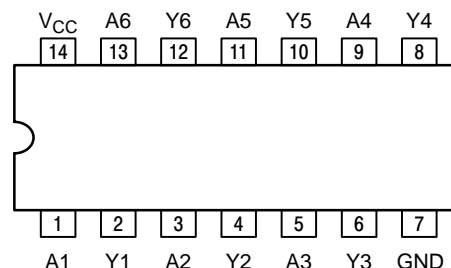
14-LEAD SOIC  
D SUFFIX  
CASE 751A



14-LEAD TSSOP  
DT SUFFIX  
CASE 948G



14-LEAD SOIC EIAJ  
M SUFFIX  
CASE 965



14-Lead Pinout (Top View)

For detailed package marking information, see the Marking Diagram section on page 5 of this data sheet.

### FUNCTION TABLE

A Input	Y Output
L	L
H	H

### ORDERING INFORMATION

Device	Package	Shipping
MC74LVX50D	SO-14	55 Units/Rail
MC74LVX50DT	TSSOP-14	96 Units/Rail
MC74LVX50M	SO EIAJ-14	50 Units/Rail

# MC74LVX50

## MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	DC Supply Voltage	− 0.5 to + 7.0	V
$V_{IN}$	DC Input Voltage	− 0.5 to + 7.0	V
$V_{OUT}$	DC Output Voltage	− 0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current $V_I < GND$	− 20	mA
$I_{OK}$	DC Output Diode Current $V_O < GND$	± 20	mA
$I_{OUT}$	DC Output Sink Current	± 25	mA
$I_{CC}$	DC Supply Current per Supply Pin	± 50	mA
$T_{STG}$	Storage Temperature Range	− 65 to + 150	°C
$T_L$	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
$T_J$	Junction Temperature under Bias	+ 150	°C
$\theta_{JA}$	Thermal Resistance (Note 1) SOIC TSSOP	125 170	°C/W
MSL	Moisture Sensitivity	Level 1	
$F_R$	Flammability Rating Oxygen Index: 30% – 35%	UL–94–VO (0.125 in)	
$V_{ESD}$	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 2000	V
$I_{Latch-Up}$	Latch-Up Performance Above $V_{CC}$ and Below GND at 85°C (Note 5)	± 300	mA

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm–by–1 inch, 2–ounce copper trace with no air flow.
2. Tested to EIA/JESD22–A114–A.
3. Tested to EIA/JESD22–A115–A.
4. Tested to JESD22–C101–A.
5. Tested to EIA/JESD78.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
$V_{CC}$	Supply Voltage	2.0	3.6	V
$V_I$	Input Voltage (Note 6)	0	5.5	V
$V_O$	Output Voltage (HIGH or LOW State)	0	$V_{CC}$	V
$T_A$	Operating Free–Air Temperature	− 40	+ 85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate $V_{CC} = 3.0\text{ V} \pm 0.3\text{ V}$	0	100	ns/V

6. Unused inputs may not be left open. All inputs must be tied to a high– or low–logic input voltage level.

NOTE: The  $\theta_{JA}$  of the package is equal to 1/Derating. Higher junction temperatures may affect the expected lifetime of the device per the table and figure below.

# MC74LVX50

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			T <sub>A</sub> ≤ 85°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		2.0 3.0 3.6	1.5 2.0 2.4			1.5 2.0 2.4		V
V <sub>IL</sub>	Low-Level Input Voltage		2.0 3.0 3.6			0.5 0.8 0.8		0.5 0.8 0.8	V
V <sub>OH</sub>	High-Level Output Voltage (V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> )	I <sub>OH</sub> = -50 μA I <sub>OH</sub> = -50 μA I <sub>OH</sub> = -4 mA	2.0 3.0 3.0	1.9 2.9 2.58	2.0 3.0		1.9 2.9 2.48		V
V <sub>OL</sub>	Low-Level Output Voltage (V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> )	I <sub>OL</sub> = 50 μA I <sub>OL</sub> = 50 μA I <sub>OL</sub> = 4 mA	2.0 3.0 3.0		0.0 0.0	0.1 0.1 0.36		0.1 0.1 0.44	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0 to 3.6			±0.1		±1.0	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	3.6			2.0		20.0	μA

## AC ELECTRICAL CHARACTERISTICS Input t<sub>r</sub> = t<sub>f</sub> = 3.0 ns

Symbol	Parameter	Test Conditions	T <sub>A</sub> = 25°C			T <sub>A</sub> ≤ 85°C		Unit
			Min	Typ	Max	Min	Max	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay, Input A to Y	V <sub>CC</sub> = 2.7 V C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		5.4 7.9	10.1 13.6	1.0 1.0	12.5 16.0	ns
		V <sub>CC</sub> = 3.3 V ± 0.3 V C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		4.1 6.6	6.2 9.7	1.0 1.0	7.5 11.5	
t <sub>OSHL</sub> t <sub>OSLH</sub>	Output-to-Output Skew (Note 7)	V <sub>CC</sub> = 2.7 V C <sub>L</sub> = 50 pF			1.5		1.5	ns
		V <sub>CC</sub> = 3.3 V ± 0.3 V C <sub>L</sub> = 50 pF			1.5		1.5	
C <sub>IN</sub>	Input Capacitance			4	10		10	pF

C <sub>PD</sub>	Power Dissipation Capacitance (Note 8)	Typical @ 25°C, V <sub>CC</sub> = 3.3 V	pF
		15	

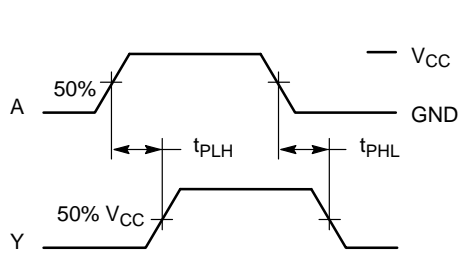
7. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

8. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

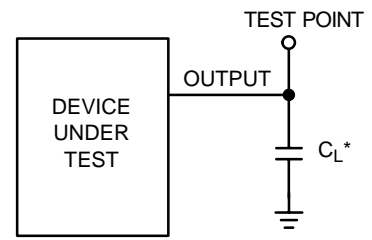
## NOISE CHARACTERISTICS Input t<sub>r</sub> = t<sub>f</sub> = 3.0 ns, C<sub>L</sub> = 50 pF, V<sub>CC</sub> = 3.3 V

Symbol	Characteristic	T <sub>A</sub> = 25°C		Unit
		Typ	Max	
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	0.3	0.5	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	-0.3	-0.5	V
V <sub>IHD</sub>	Minimum High Level Dynamic Input Voltage		2.0	V
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage		0.8	V

# MC74LVX50

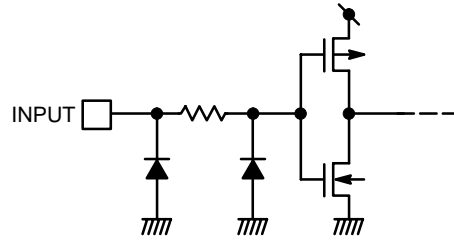


**Figure 3. Switching Waveforms**



\*Includes all probe and jig capacitance

**Figure 4. Test Circuit**

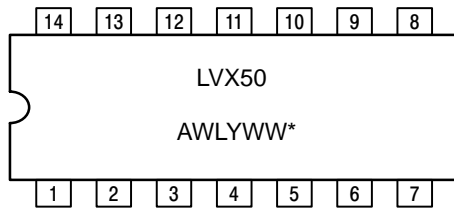


**Figure 5. Input Equivalent Circuit**

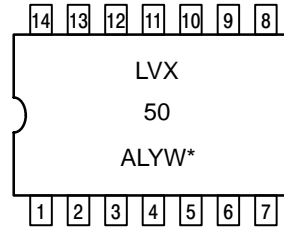
# MC74LVX50

## MARKING DIAGRAMS

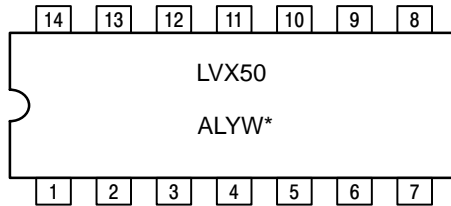
(Top View)



**14-LEAD SOIC  
D SUFFIX  
CASE 751A**



**14-LEAD TSSOP  
DT SUFFIX  
CASE 948G**



**14-LEAD SOIC EIAJ  
M SUFFIX  
CASE 965**

\*See Applications Note #AND8004/D for date code and traceability information.

# MC74LVX50

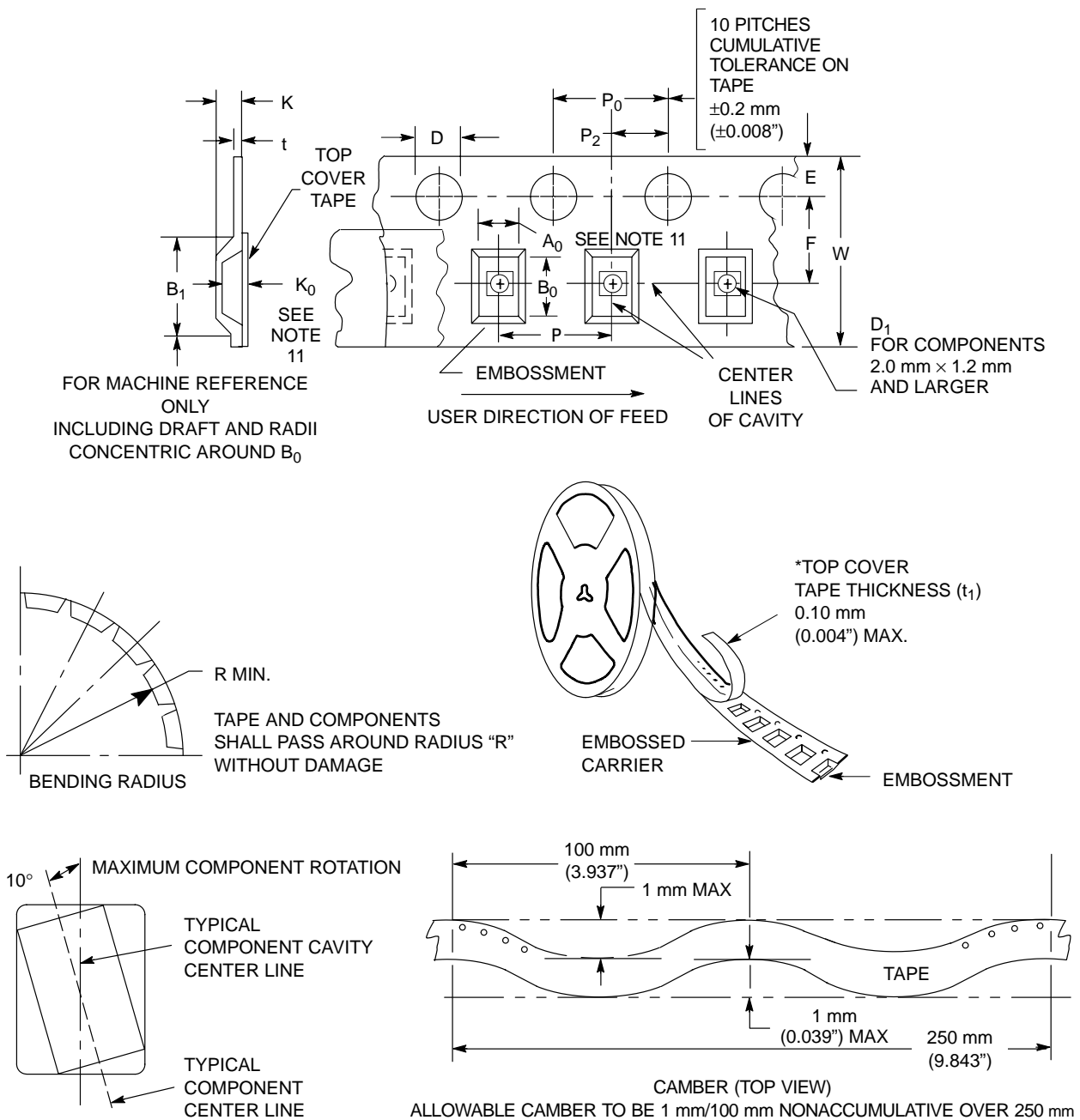
## EMBOSSED CARRIER DIMENSIONS (See Notes 9 and 10)

Tape Size	B <sub>1</sub> Max	D	D <sub>1</sub>	E	F	K	P	P <sub>0</sub>	P <sub>2</sub>	R	T	W
8 mm	4.35 mm (0.179")	1.5 mm + 0.1 -0.0 (0.059" +0.004 -0.0)	1.0 mm Min (0.179")	1.75 mm ±0.1 (0.069 ±0.004")	3.5 mm ±0.5 (1.38 ±0.002")	2.4 mm Max (0.094")	4.0 mm ±0.10 (0.157 ±0.004")	4.0 mm ±0.1 (0.157 ±0.004")	2.0 mm ±0.1 (0.079 ±0.004")	25 mm (0.98")	0.6 mm (0.024)	8.3 mm (0.327)
12 mm	8.2 mm (0.323")		1.5 mm Min (0.060)		5.5 mm ±0.5 (0.217 ±0.002")	6.4 mm Max (0.252")	4.0 mm ±0.10 (0.157 ±0.004") 8.0 mm ±0.10 (0.315 ±0.004")			30 mm (1.18")		12.0 mm ±0.3 (0.470 ±0.012")
16 mm	12.1 mm (0.476")				7.5 mm ±0.10 (0.295 ±0.004")	7.9 mm Max (0.311")	4.0 mm ±0.10 (0.157 ±0.004") 8.0 mm ±0.10 (0.315 ±0.004") 12.0 mm ±0.10 (0.472 ±0.004")					16.3 mm (0.642)
24 mm	20.1 mm (0.791")				11.5 mm ±0.10 (0.453 ±0.004")	11.9 mm Max (0.468")	16.0 mm ±0.10 (0.63 ±0.004")					24.3 mm (0.957)

9. Metric Dimensions Govern—English are in parentheses for reference only.

10. A<sub>0</sub>, B<sub>0</sub>, and K<sub>0</sub> are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity

# MC74LVX50



11.  $A_0$ ,  $B_0$ , and  $K_0$  are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity

**Figure 6. Carrier Tape Specifications**

# MC74LVX50

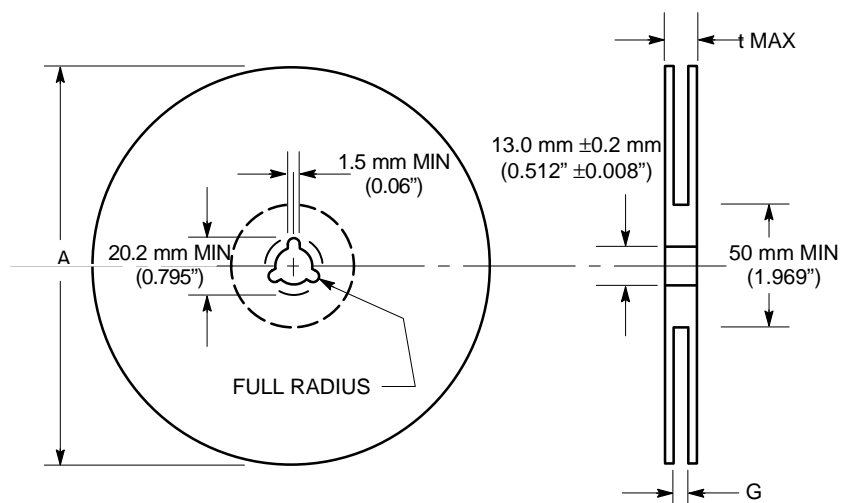


Figure 7. Reel Dimensions

## REEL DIMENSIONS

Tape Size	T&R Suffix	A Max	G	t Max
8 mm	T1, T2	178 mm (7")	8.4 mm, +1.5 mm, -0.0 (0.33" + 0.059", -0.00)	14.4 mm (0.56")
8 mm	T3, T4	330 mm (13")	8.4 mm, +1.5 mm, -0.0 (0.33" + 0.059", -0.00)	14.4 mm (0.56")
12 mm	R2	330 mm (13")	12.4 mm, +2.0 mm, -0.0 (0.49" + 0.079", -0.00)	18.4 mm (0.72")
16 mm	R2	360 mm (14.173")	16.4 mm, +2.0 mm, -0.0 (0.646" + 0.078", -0.00)	22.4 mm (0.882")
24 mm	R2	360 mm (14.173")	24.4 mm, +2.0 mm, -0.0 (0.961" + 0.078", -0.00)	30.4 mm (1.197")

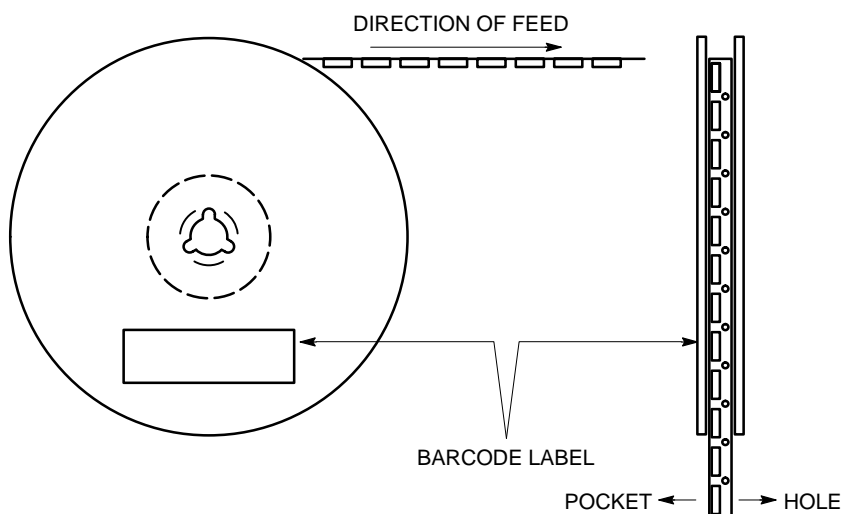
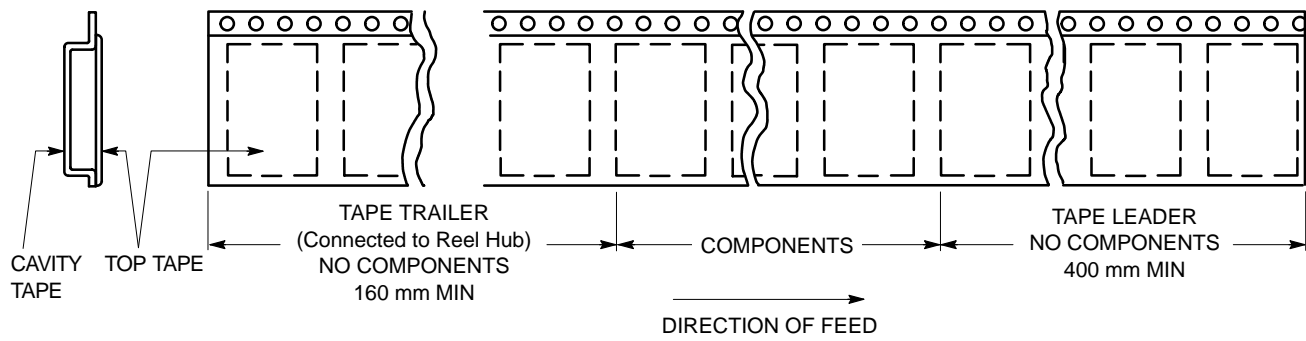


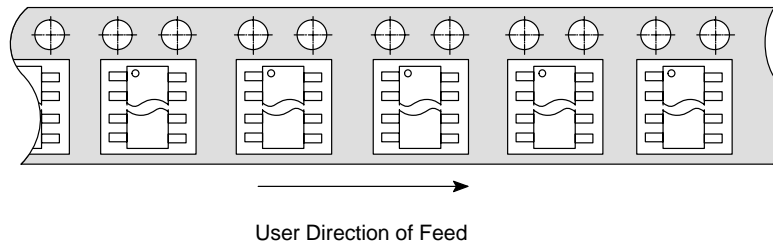
Figure 8. Reel Winding Direction



## MC74LVX50



**Figure 9. Tape Ends for Finished Goods**



**Figure 10. TSSOP and SOIC R2 Reel Configuration/Orientation**

### TAPE UTILIZATION BY PACKAGE

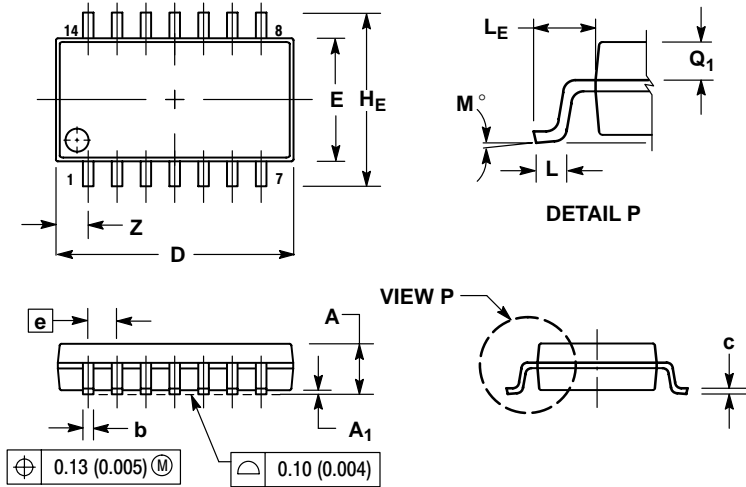
Tape Size	SOIC	TSSOP	QFN	SC88A / SOT-353 SC88/SOT-363
8 mm				5-, 6-Lead
12 mm	8-Lead	8-, 14-, 16-Lead	8-, 14-, 16-Lead	
16 mm	14-, 16-Lead	20-, 24-Lead	20-, 24-Lead	
24 mm	18-, 20-, 24-, 28-Lead	48-, 56-Lead	48-, 56-Lead	



# MC74LVX50

## PACKAGE DIMENSIONS


SO EIAJ-14  
M SUFFIX  
CASE 965-01  
ISSUE O



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H <sub>E</sub>	7.40	8.20	0.291	0.323
0.50	0.50	0.85	0.020	0.033
L <sub>E</sub>	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z	---	1.42	---	0.056

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